



Description

The NTMFS4837NT1G uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

$V_{DS} = 30V$ $I_D = 120A$

$R_{DS(ON)} < 2.6m\Omega$ $V_{GS}=10V$

Application

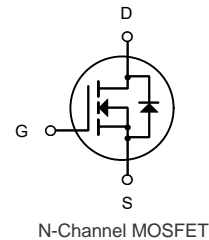
Battery protection

Load switch

Uninterruptible power supply



DFN5X6-8L



Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
NTMFS4837NT1G	DFN5X6-8L	HXY MOSFET	5000

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	30	V
V_{GS}	Gate-Source Voltage	± 20	V
$I_D@T_C=25^\circ C$	Continuous Drain Current, $V_{GS} @ 10V$	120	A
$I_D@T_C=100^\circ C$	Continuous Drain Current, $V_{GS} @ 10V$	57	A
I_{DM}	Pulsed Drain Current	360	A
EAS	Single Pulse Avalanche Energy	125	mJ
P_D	Total Power Dissipation ⁴	115	W
T_{STG}	Storage Temperature Range	-55 to 175	°C
T_J	Operating Junction Temperature Range	-55 to 175	°C
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	62	°C/W
$R_{\theta JC}$	Thermal Resistance Junction-Case ²	1.3	°C/W



Electrical Characteristics (T_J=25°C, unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	30	---	---	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{GS} =0V, V _{DS} =30V	---	---	1	μA
I _{GSS}	Gate-Source Leakage Current	V _{GS} =±20V, V _{DS} =0A	---	---	±100	nA
V _{GS(th)}	GateSource Threshold Voltage	V _{GS} =V _{DS} , I _D =250μ A	1	1.6	2.5	V
R _{DS(ON)}	Drain-Source On Resistance ²	V _{GS} =10V, I _D =20A	---	2.6	3.3	mΩ
		V _{GS} =4.5V, I _D =10A	---	3.8	5	
C _{iss}	Input Capacitance	V _{DS} =25V, V _{GS} =0V, f=1MHz	---	2218	---	pF
C _{oss}	Output Capacitance		---	480	---	
C _{rss}	Reverse Transfer Capacitance		---	340	---	
t _{d(on)}	Turn-On Delay Time ^{3,4}	V _{DD} =15V, I _D =15A, R _G =3.3Ω V _{GS} =10V	---	12.6	---	ns
t _r	Rise Time ^{3,4}		---	19.5	---	ns
t _{d(off)}	Turn-Off Delay Time ^{3,4}		---	42.8	---	ns
t _f	Fall Time ^{3,4}		---	13.2	---	ns
Q _g	Total Gate Charge ^{3,4}	V _{GS} =4.5V, V _{DS} =15V, I _D =20A	---	24	---	nC
Q _{gs}	Gate-Source Charge ^{3,4}		---	4.2	---	nC
Q _{gd}	Gate-Drain "Miller" Charge ^{3,4}		---	13	---	nC
V _{SD}	Source-Drain Diode Forward Voltage ³	V _{GS} =0V, I _S =1A	---	---	1	V
I _S	Continuous Source Current	V _G =V _D =0V, Force Current	---	---	120	A
I _{SM}	Pulsed Source Current		---	---	360	A
T _{rr}	Reverse Recovery Time	V _{GS} =30V, I _S =1A, di/dt=100A/μs T _J =25°C	---	258	---	NS
Q _{rr}	Reverse Recovery Charge		---	324	---	NC

Notes:

1. Repetitive Rating : Pulsed width limited by maximum junction temperature.
2. V_{DD}=25V, V_{GS}=10V, L=0.1mH, I_{AS}=50A., R_G=25Ω, Starting T_J=25°C.
3. The data tested by pulsed, pulse width ≤ 300us, duty cycle ≤ 2%.
4. Essentially independent of operating temperature.



Typical Characteristics

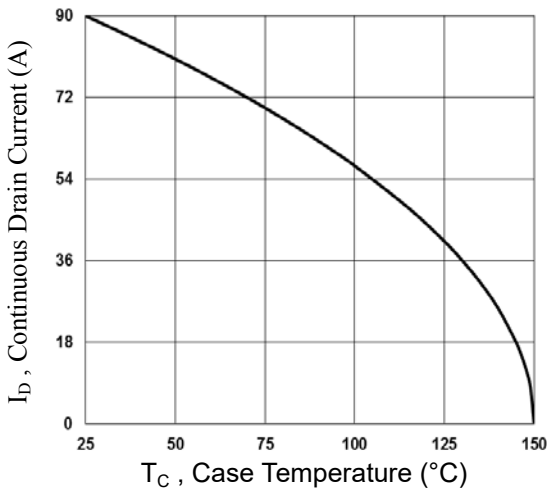


Fig.1 Continuous Drain Current vs. T_C

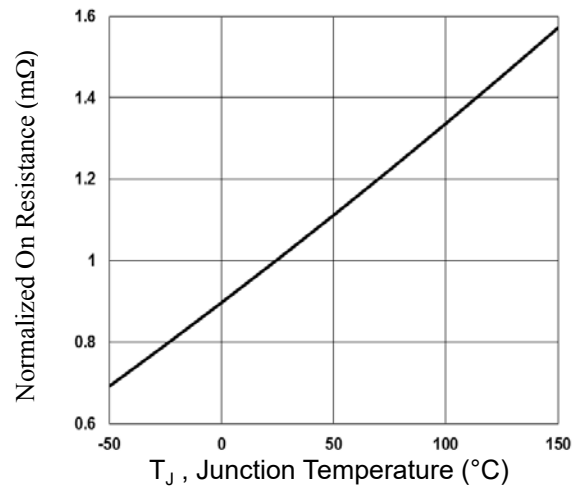


Fig.2 Normalized $R_{DS(on)}$ vs. T_J

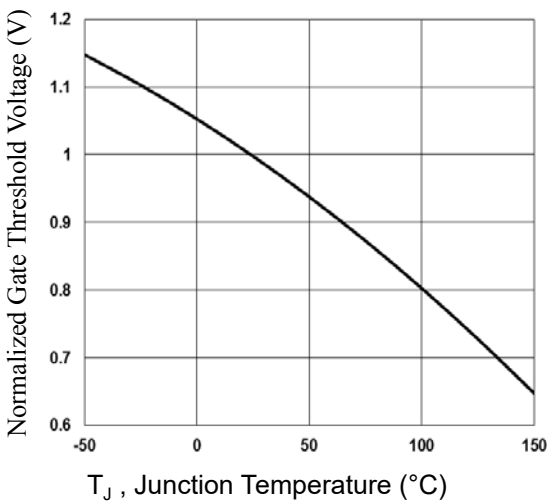


Fig.3 Normalized V_{th} vs. T_J

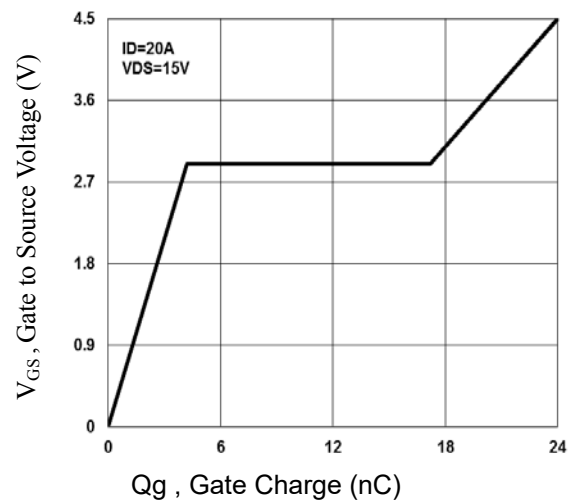


Fig.4 Gate Charge Waveform

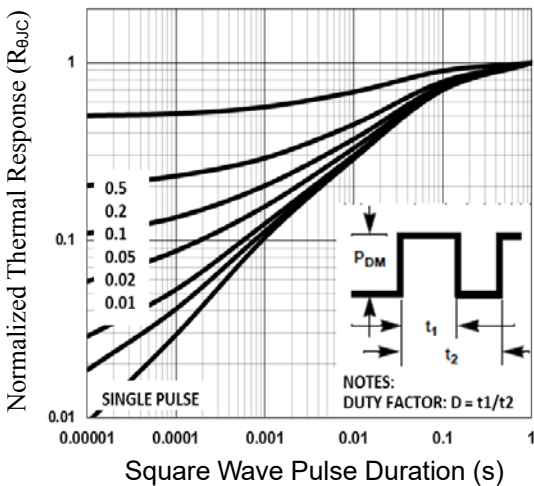


Fig.5 Normalized Transient Impedance

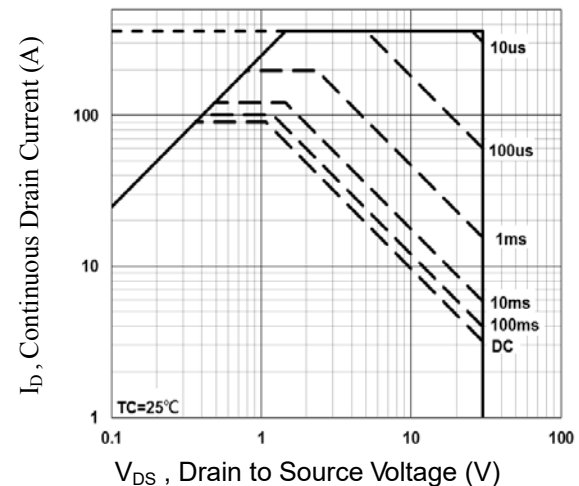


Fig.6 Maximum Safe Operation Area

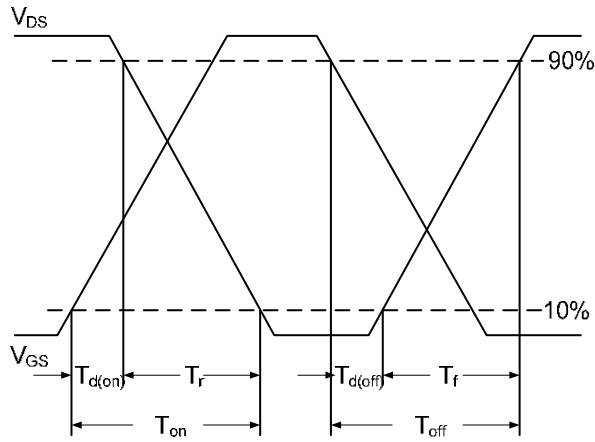


Fig.7 Switching Time Waveform

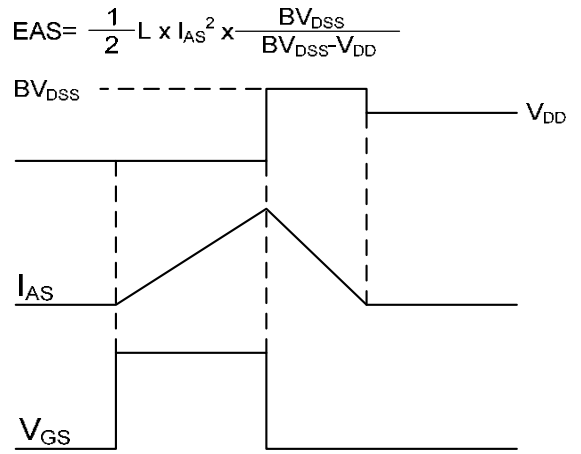
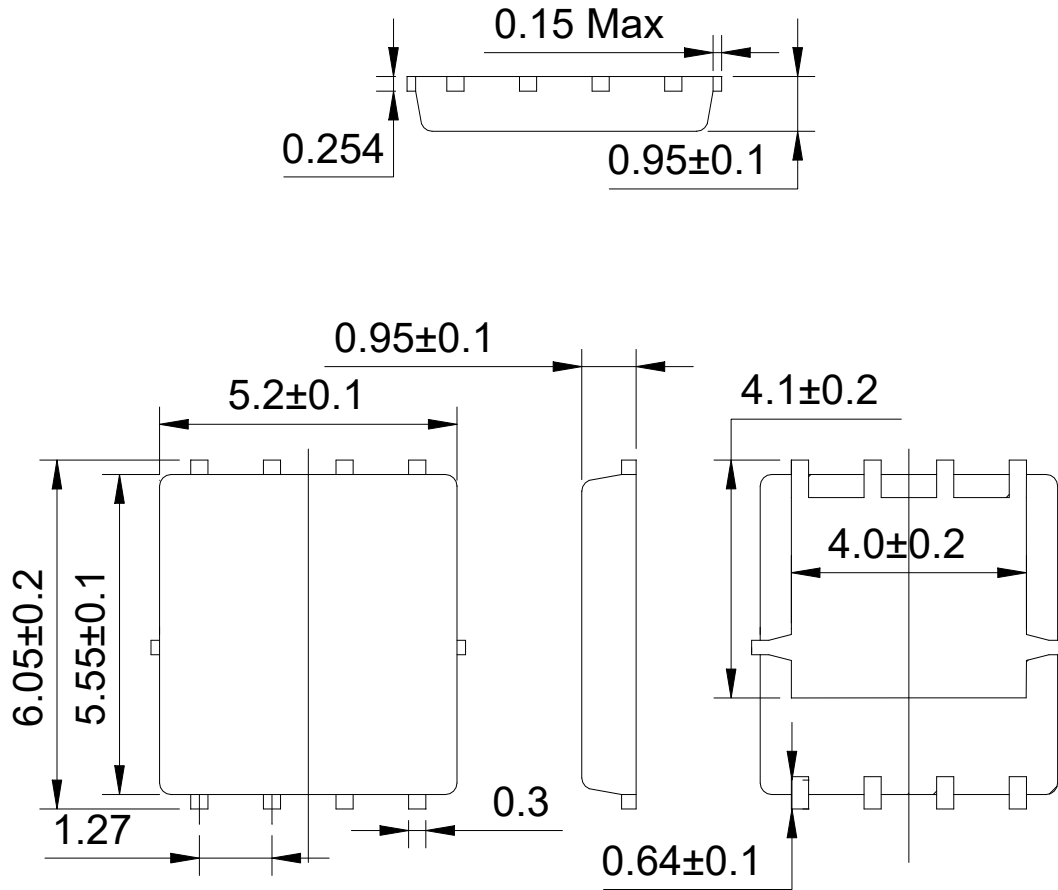


Fig.8 EAS Waveform



DFN5X6-8L Package Information

Unit:mm





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